IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Applica	tion of: Seiichi NAGATA)	Confirmation No.: 4585								
U.S. Applica	tion No.: 10/551,195)	Group Art Unit: Unassigned								
Filed: Septer	tember 29, 2005) Examiner: Unassigned										
For: SILICO	N SUBSTRATE AND METHOD OF	FORM	ING THE SAME								
U.S. Patent a	er for Patents nd Trademark Office Vindow Mail Stop: PCT VA 22314										
Sir: INFORMATION DISCLOSURE STATEMENT (IDS)											
Under 37 C.F.R. § 1.97(b): Pursuant to 37 C.F.R. §§ 1.56 and 1.97(b), Applicant prings to the attention of the Examiner the documents listed on the attached PTO Form 1449. To the undersigned's knowledge, this IDS is being filed before the mailing date of a first Office Action on the merits, before the mailing date of a first Office Action on the merits after filing an RCE under § 1.114, or within three months of the application filing date.											
to the attentice s being filed mailing date	on of the Examiner the documents liste	ed on that, to the	. §§ 1.56 and 1.97(c), Applicant brings e attached PTO Form 1449. This IDS e undersigned's knowledge, before the ce, or another action that closes								
	The fee of \$180.00 set forth in § 1.17	7(p) is i	ncluded herein; or								
	Applicant submits that each item of information contained in this IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this IDS.										
orings to the	r 37 C.F.R. § 1.97(d): Pursuant to 37 attention of the Examiner the documer eing filed after the events recited in § 1	nts liste	d on the attached PTO Form 1449.								
	The fee of \$180.00 set forth in § 1.17	7(p) is i	ncluded herein; and								
	Applicant submits that each item of information contained in this IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this IDS.										

Attorney Docket No.: 46884-5429

Page 2

Under 37 C.F.R. § 1.97(i): Pursuant to 37 C.F.R. §§ 1.56 and 1.97(i), Applicant brings to the attention of the Examiner the documents listed on the attached PTO Form 1449. This IDS is being filed after the events recited in § 1.97(d). Applicant requests that the IDS be placed in the file.

A search report or other listing of documents from a counterpart, related, or other application dated <u>July 6, 2004</u> and having documents cited thereon is attached for the Examiner's consideration. Any of these documents not previously cited, and any additional documents are listed on the PTO Form 1449.

Applicant respectfully requests that the Examiner consider the listed documents and evidence that consideration by making appropriate notations on the attached form. As for any document listed on the accompanying PTO-1449 that is in a language other than English, relevance can be understood from an enclosed English abstract or at least partial translation or from mention in the specification or in a search report for a corresponding application.

This submission does not represent that a search has been made or that no better art exists and does not constitute an admission that any of the listed documents are material or constitute "prior art." If it should be determined that any of the listed documents do not constitute "prior art" under United States law, Applicant reserve the right to present to the Office the relevant facts and law regarding the appropriate status of such documents.

Applicant further reserves the right to take appropriate action to establish the patentability of the disclosed invention over the listed documents, should any of the documents be applied against the claims of the present application.

Except for issue fees payable under 37 C.F.R. § 1.18, the Commissioner is hereby authorized by this paper to charge any additional fees during the entire pendency of this Application, including fees due under 37 C.F.R. § 1.16 and 1.17 which may be required and including any required extension of time fees, or credit any overpayment to Deposit Account No. 50-0573. This paragraph is intended to be a CONSTRUCTIVE PETITION FOR EXTENSION OF TIME in accordance with 37 C.F.R. § 1.136(a)(3).

Respectfully submitted,

DRINKER, BIDDLE & REATH LLP

Dated: July 17, 2006

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Peter J. Sistare

Registration No. 48,183

CUSTOMER NO. 055694 DRINKER, BIDDLE & REATH LLP

1500 K Street, N.W., Suite 1100 Washington, D.C. 20005-1209

Tel: 202.842.8800; Fax: 202.842.8465

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